



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)} Max	I _D T _C = +25°C	
-40V	$11m\Omega @ V_{GS} = -10V$	-35A	
- 4 0V	$15m\Omega @ V_{GS} = -4.5V$	-30A	

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}), yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- DC-DC Converters
- Power Management Functions
- Backlighting

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test In Production
- · Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

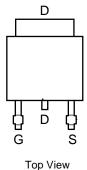
Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.33 grams (Approximate)

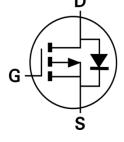
TO252 (DPAK)



Top View



Pin-Out



Equivalent Circuit

Ordering Information (Notes 4 & 5)

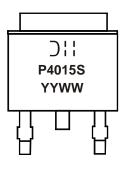
Part Number	Compliance	Case	Packaging
DMP4015SK3Q-13	Automotive	TO252 (DPAK)	2,500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



Marking Information



Dil = Manufacturer's Marking
P4015S = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 13 = 2013)
WW = Week (01 - 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V _{DSS}	-40	V		
Gate-Source Voltage	V _{GSS}	±25	V		
Continuous Drain Current (Note 6) $V_{GS} = -10V$ Steady $T_C = +25^{\circ}C$ State $T_C = +70^{\circ}C$		I _D	-35 -27	А	
Continuous Drain Current (Note 6) \/ 10\/	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-14 -11	А
Continuous Drain Current (Note 6) V _{GS} = -10V	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-22 -18	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	-100	Α		
Maximum Body Diode Forward Current (Note 6)	Is	-5.5	Α		
Avalanche Current (Note 7)	I _{AS}	-22	Α		
Avalanche Energy (Note 7)	E _{AS}	242	mJ		

Thermal Characteristics

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	D-	3.5	- W
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	P_D	2.2	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	D	36	
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	15	°C/W
Thermal Resistance, Junction to Case (Note 6)	Steady State	$R_{ heta JC}$	4.5	
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C

Notes: 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

7. UIS in production with L = 0.1 mH, $T_J = +25 ^{\circ}\text{C}$.



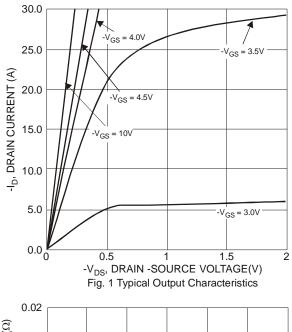
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

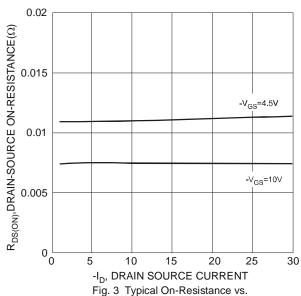
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	-40	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-1	μΑ	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(th)}	-1.5	-2	-2.5	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance	ם		7	11	mΩ	$V_{GS} = -10V, I_D = -9.8A$	
Static Drain-Source Off-Resistance	R _{DS(ON)}		9	15	11122	$V_{GS} = -4.5V, I_D = -9.8A$	
Forward Transfer Admittance	Y _{fs}	_	26	_	S	$V_{DS} = -20V, I_{D} = -9.8A$	
Diode Forward Voltage	V_{SD}		-0.7	-1	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}		4,234	_		$V_{DS} = -20V$, $V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	_	1,036	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	526	_			
Gate Resistance	R_G	_	7.77	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	_	47.5	_		V 20V V 5V	
Gate-Source Charge	Q_{gs}	_	14.2	_	nC	$V_{DS} = -20V, V_{GS} = -5V$ $I_{D} = -9.8A$	
Gate-Drain Charge	Q _{gd}	_	13.5	_			
Turn-On Delay Time	t _{D(on)}	_	13.2	_		$V_{GS} = -10V, V_{DD} = -20V,$ $R_{G} = 6\Omega, I_{D} = -1A$	
Turn-On Rise Time	t _r	_	10	_	nS		
Turn-Off Delay Time	t _{D(off)}	_	302.7	_	115		
Turn-Off Fall Time	t _f	_	137.9	_			

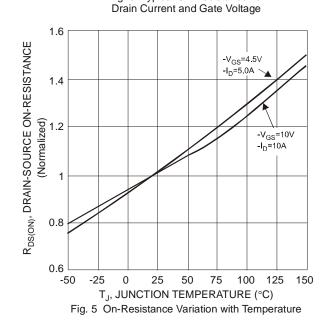
Notes:

^{8.} Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to production testing.

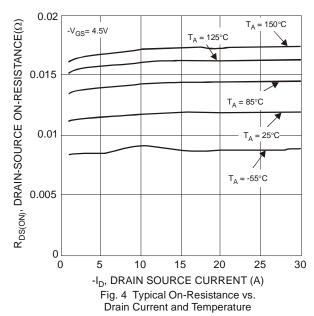








30 T_A = 150°C V_{DS}= -5.0V T_A = 25°C 25 T_A = 125°C -I_D, DRAIN CURRENT (A) 20 T_A = -55°C 15 T_A = 85°C 10 5 0 0.5 1.5 2 2.5 0 3 3.5 4 -V_{GS}, GATE-SOURCE VOLTAGE (V) Fig. 2 Typical Transfer Characteristics



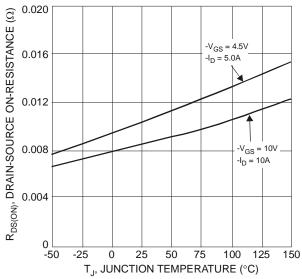


Fig. 6 On-Resistance Variation with Temperature



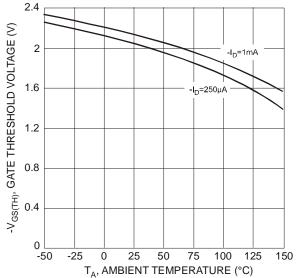
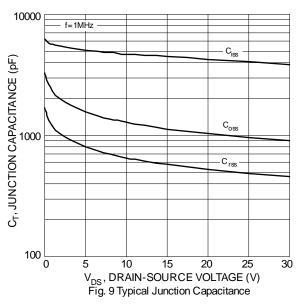
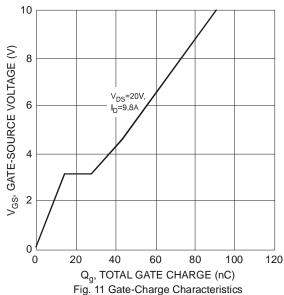
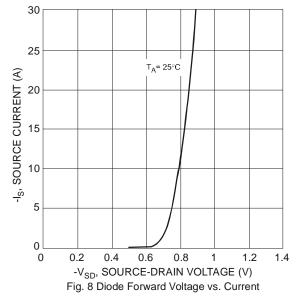


Fig. 7 Gate Threshold Variation vs. Ambient Temperature







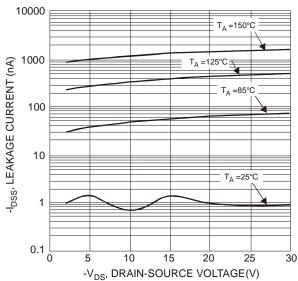


Fig. 10 Typical Drain-Source Leakage Current vs. Voltage

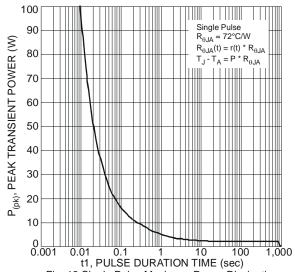
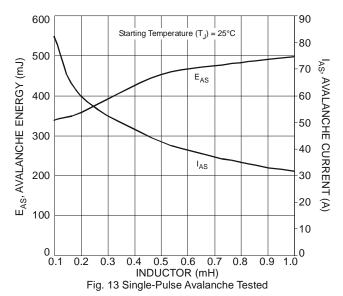
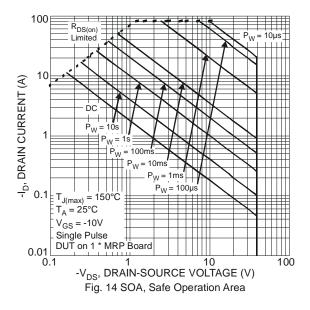
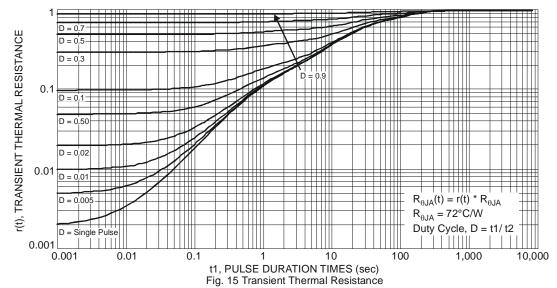


Fig. 12 Single Pulse Maximum Power Dissipation







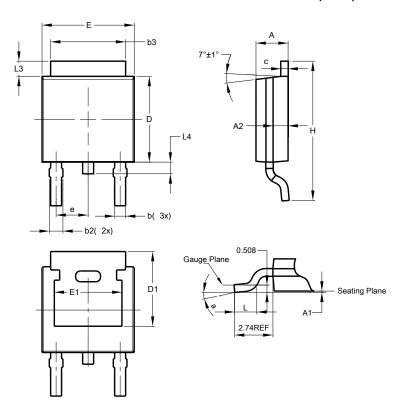




Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

TO252 (DPAK)

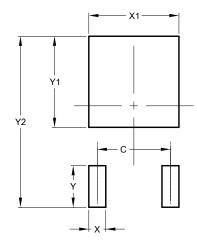


TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A 1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	_	_		
е	_	_	2.286		
Е	6.45	6.70	6.58		
E1	4.32	_	_		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	_		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

TO252 (DPAK)



Dimensions	Value (in mm)			
С	4.572			
Х	1.060			
X1	5.632			
Υ	2.600			
Y1	5.700			
Y2	10.700			



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